LME49724 High Performance, High Fidelity, Fully-Differential Audio Operational Amplifier

Check for Samples: LME49724

FEATURES

- **Drives 600Ω loads with full output signal swing**
- **Optimized for superior audio signal fidelity**
- **Output short circuit protection**
- **PSRR and CMRR exceed 100dB (typ)**
- **Available in PSOP package**

APPLICATIONS

- **Ultra high quality audio amplification**
- **High fidelity preamplifiers and active filters**
- **Simple single-ended to differential conversion**
- **State of the art D-to-A converters**
- **State of the art A-to-D input amplifiers**
- **Professional Audio**
- **High fidelity equalization and crossover networks**
- **High performance line drivers and receivers**

DESCRIPTION

The LME49724 is an ultra-low distortion, low noise, high slew rate fully-differential operational amplifier optimized and fully specified for high performance, high fidelity applications. Combining advanced leading-edge process technology with state of the art circuit design, the LME49724 fully-differential audio operational amplifier delivers superior audio signal amplification for outstanding audio performance. The LME49724 combines extremely low voltage noise density (2.1nV/√Hz) with vanishingly low THD+N (0.00003%) to easily satisfy the most demanding audio applications. To ensure that the most challenging loads are driven without compromise, the LME49724 has a high slew rate of ±18V/µs and an output current capability of ±80mA. Further, dynamic range is maximized by an output stage that drives 600Ω loads to $52V_{P-P}$ while operating on a ±15V supply voltage.

The LME49724's outstanding CMRR (102dB), PSRR (125dB), and V_{OS} (0.2mV) results in excellent operational amplifier DC performance.

The LME49724 has a wide supply range of ±2.5V to ±18V. Over this supply range the LME49724's input circuitry maintains excellent common-mode and power supply rejection, as well as maintaining its low input bias current. The LME49724 is unity gain stable. This Fully-Differential Audio Operational Amplifier achieves outstanding AC performance while driving complex loads with capacitive values as high as 100pF.

Table 1. Key Specifications

	VALUE	UNIT
Power Supply Voltage Range	±2.5V to ±18V	V
THD+N (A_V = 1, V_{OUT} = $3V_{RMS}$, f_{IN} = 1kHz)		
R_L = 2kΩ	0.00003% (typ)	
R_L = 600Ω	0.00003% (typ)	
Input Noise Density	2.1nV/√Hz (typ)	
Slew Rate	±18V/µs (typ)	
Gain Bandwidth Product	50	MHz (typ)
Open Loop Gain (R_L = 600Ω)	125	dB (typ)
Input Bias Current	60nA (typ)	
Input Offset Voltage	0.2mV (typ)	
DC Gain Linearity Error	0.000009%	

Typical Application

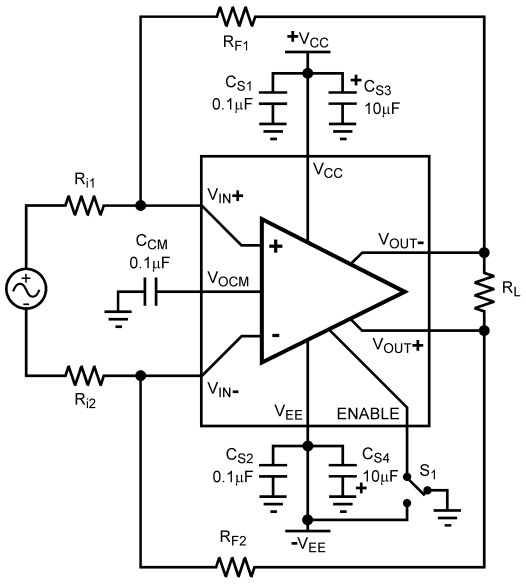

Figure 1. Typical Application Circuit

Connection Diagram

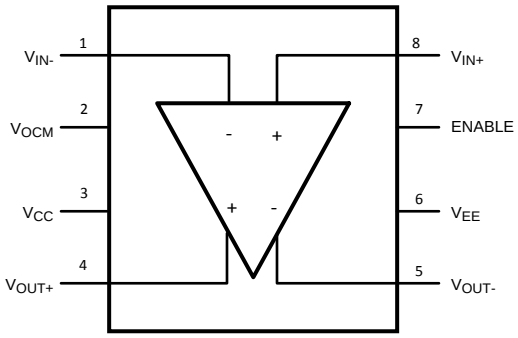

Figure 2. Order Number LME49724MR
See NS Package Number MRA08B

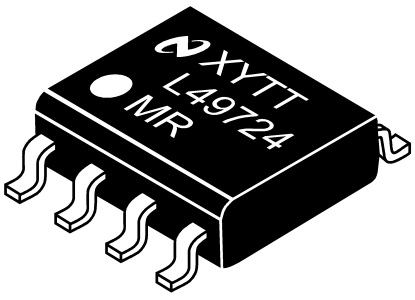

Figure 3. PSOP Marking (Top View)

Pin Functions

Pin Descriptions

Pin	Name	Pin Function	Type
1	V_{IN-}	Input pin	Analog Input
2	V_{OCM}	Sets the output DC voltage. Internally set by a resistor divider to the midpoint of the voltages on the V_{CC} and V_{EE} pins. Can be forced externally to a different voltage (50kΩ input impedance).	Analog Input
3	V_{CC}	Positive power supply pin.	Power Supply
4	V_{OUT+}	Output pin. Signal is inverted relative to V_{IN-} where the feedback loop is connected.	Analog Output
5	V_{OUT-}	Output pin. Signal is inverted relative to V_{IN+} where the feedback loop is connected.	Analog Output
6	V_{EE}	Negative power supply pin or ground for a single supply configuration.	Power Supply
7	ENABLE	Enables the LME49724 when the voltage is greater than 2.35V above the voltage on the V_{EE} pin. Disable the LME49724 by connecting to the same voltage as on the V_{EE} pin which will reduce current consumption to less than 0.3mA (typ).	Analog Input
8	V_{IN+}	Input pin	Analog Input
Exposed Pad		Exposed pad for improved thermal performance. Connect to the same potential as the V_{EE} pin or electrically isolate.	

These devices have limited built-in ESD protection. The leads should be shorted together or the device placed in conductive foam during storage or handling to prevent electrostatic damage to the MOS gates.

Absolute Maximum Ratings (1) (2)

Power Supply Voltage ($V_S = V_{CC} + \|V_{EE}\|$)	38V
Storage Temperature	−65°C to 150°C
Input Voltage	(V_{EE}) – 0.7V to (V_{CC}) + 0.7V
Output Short Circuit	Continuous
Power Dissipation (Note 3)	Internally Limited
ESD Rating (Note 4)	2000V
ESD Rating (Note 5)	200V
Junction Temperature (T_{JMAX})	150°C
Soldering Information	
Vapor Phase (60sec.)	215°C
Infrared (60sec.)	220°C
Thermal Resistance	
θ_{JA} (MR)	49.6°C/W

(1) *Absolute Maximum Ratings* indicate limits beyond which damage to the device may occur, including inoperability and degradation of device reliability and/or performance. Functional operation of the device and/or non-degradation at the *Absolute Maximum Ratings* or other conditions beyond those indicated in the *Recommended Operating Conditions* is not implied. The *Recommended Operating Conditions* indicate conditions at which the device is functional and the device should not be operated beyond such conditions. All voltages are measured with respect to the ground pin, unless otherwise specified.

(2) The *Electrical Characteristics* tables list guaranteed specifications under the listed *Recommended Operating Conditions* except as otherwise modified or specified by the *Electrical Characteristics Conditions* and/or Notes. Typical specifications are estimations only and are not guaranteed.

Operating Ratings (1) (2)

Temperature Range	
$T_{MIN} \le T_A \le T_{MAX}$	$-40°C \le T_A \le +85°C$
Supply Voltage Range	$\pm 2.5V \le V_S \le \pm 18V$

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(2) The *Electrical Characteristics* tables list guaranteed specifications under the listed *Recommended Operating Conditions* except as otherwise modified or specified by the *Electrical Characteristics Conditions* and/or Notes. Typical specifications are estimations only and are not guaranteed.

Electrical Characteristics (1) (2)

The following specifications apply for V_S = ±15V, R_L = 2kΩ, f_{IN} = 1kHz, and T_A = 25°C, unless otherwise specified.

Symbol	Parameter	Conditions	LME49724		Units (Limits)
			Typical (3)	Limit (4)	
POWER SUPPLY					
V_S	Operating Power Supply			±2.5V ±18V	V (min) V (max)
I_{CCQ}	Total Quiescent Current	V_O = 0V, I_O = 0mA Enable = GND Enable = V_{EE}	 10 0.3	 15 0.5	 mA (max) mA (max)
PSRR	Power Supply Rejection Ratio	V_S = ±5V to ±15V (Note 8)	125	95	dB (min)
V_{ENIH}	Enable High Input Voltage	Device active, T_A = 25°C (Note 9)	V_{EE} + 2.35		V
V_{ENIL}	Enable Low Input Voltage	Device disabled, T_A = 25°C (Note 9)	V_{EE} + 1.75		V
DYNAMIC PERFORMANCE					
THD+N	Total Harmonic Distortion + Noise	A_V = 1, V_{OUT} = 3V_{RMS} R_L = 2kΩ R_L = 600Ω	 0.00003 0.00003	 0.00009	 % % (max)
IMD	Intermodulation Distortion	A_V = 1, V_{OUT} = 3V_{RMS} Two-tone, 60Hz & 7kHz 4:1	0.0005		%
GBWP	Gain Bandwidth Product		50	35	MHz (min)
FPBW	Full Power Bandwidth	V_{OUT} = 1V_{P-P}, –3dB referenced to output magnitude at f = 1kHz	13		MHz
SR	Sew Rate	R_L = 2kΩ	±18	±13	V/µs (min)
t_S	Settling time	A_V = –1, 10V step, C_L = 100pF settling time to 0.1%	0.2		µs
A_{VOL}	Open-Loop Voltage Gain	–10V < V_{OUT} < 10V, R_L = 600Ω	125	100	dB (min)
		–10V < V_{OUT} < 10V, R_L = 2kΩ	125		dB
		–10V < V_{OUT} < 10V, R_L = 10kΩ	125		dB
NOISE					
e_N	Equivalent Input Noise Voltage	f_{BW} = 20Hz to 20kHz	0.30	0.64	µV_{RMS} (max)
	Equivalent Input Noise Density	f = 1kHz f = 10Hz	2.1 3.7		nV/√Hz (max)
INPUT CHARACTERISTICS					
V_{OS}	Offset Voltage		±0.2	±1	mV (max)
$\Delta V_{OS}/\Delta Temp$	Average Input Offset Voltage Drift vs Temperature	–40°C ≤ T_A ≤ 85°C	0.5		µV/°C
I_B	Input Bias Current	V_{CM} = 0V	60	200	nA (max)
I_{OS}	Input Offset Current	V_{CM} = 0V	10	65	nA (max)
$\Delta I_{OS}/\Delta Temp$	Input Bias Current Drift vs Temperature	–40°C ≤ T_A ≤ 85°C	0.1		nA/°C
V_{IN-CM}	Common-Mode Input Voltage Range		±14	V_{CC} – 1.5 V_{EE} + 1.5	V (min) V (min)
CMRR	Common-Mode Rejection	–10V < V_{CM} < 10V	102	95	dB (min)

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(2) The *Electrical Characteristics* tables list guaranteed specifications under the listed *Recommended Operating Conditions* except as otherwise modified or specified by the *Electrical Characteristics Conditions* and/or Notes. Typical specifications are estimations only and are not guaranteed.

(3) Typical values represent most likely parametric norms at T_A = +25ºC, and at the *Recommended Operation Conditions* at the time of product characterization and are not guaranteed.

(4) Datasheet min/max specification limits are guaranteed by test or statistical analysis.

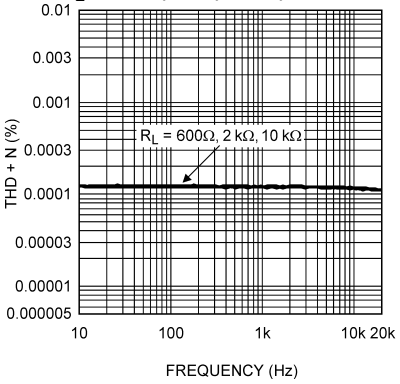
Electrical Characteristics [1] [2] (continued)

The following specifications apply for V_S = ±15V, R_L = 2kΩ, f_{IN} = 1kHz, and T_A = 25°C, unless otherwise specified.

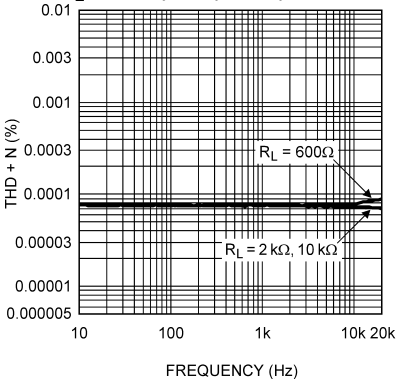
Symbol	Parameter	Conditions	LME49724		Units (Limits)
			Typical [3]	Limit [4]	
Z_{IN}	Differential Input Impedance		16		kΩ
	Common-Mode Input Impedance	–10V < V_{CM} < 10V	500		MΩ
OUTPUT CHARACTERISTICS					
V_{OUTMAX}	Maximum Output Voltage Swing	R_L = 600Ω	52	50	V_{P-P} (min)
		R_L = 2kΩ	52		V_{P-P}
		R_L = 10kΩ	53		V_{P-P}
I_{OUT-CC}	Instantaneous Short Circuit Current		80		mA
R_{OUT}	Output Impedance	f_{IN} = 10kHz Closed-Loop Open-Loop	 0.01 23		 Ω Ω
C_{LOAD}	Capacitive Load Drive Overshoot	C_L = 100pF	5		%

Typical Performance Characteristics

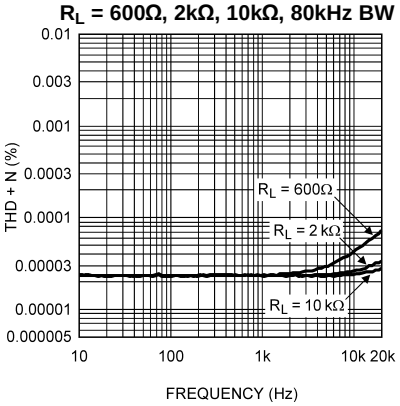
THD+N vs Frequency
V_S = ±2.5V, V_O = 0.5V_{RMS}, Differential Input
R_L = 600Ω, 2kΩ, 10kΩ, 80kHz BW



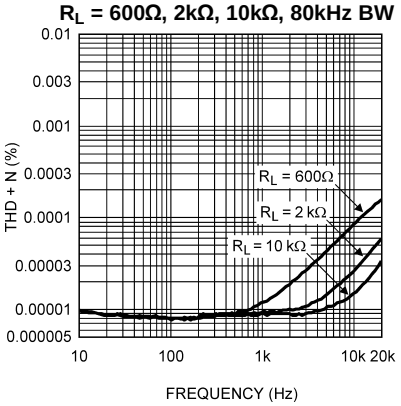
THD+N vs Frequency
V_S = ±2.5V, V_O = 0.8V_{RMS}, Differential Input
R_L = 600Ω, 2kΩ, 10kΩ, 80kHz BW



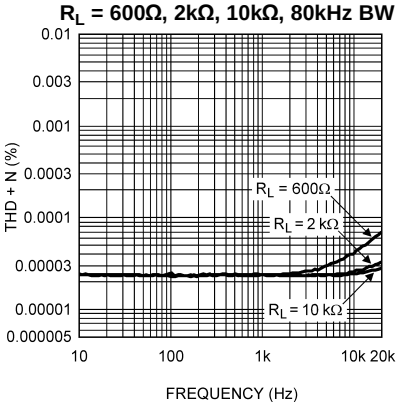
THD+N vs Frequency
V_S = ±15V, V_O = 3V_{RMS}, Differential Input
R_L = 600Ω, 2kΩ, 10kΩ, 80kHz BW



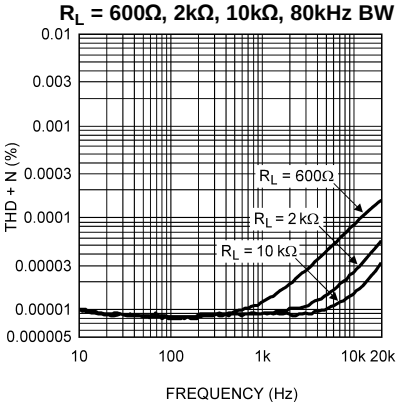
THD+N vs Frequency
V_S = ±15V, V_O = 10V_{RMS}, Differential Input
R_L = 600Ω, 2kΩ, 10kΩ, 80kHz BW



THD+N vs Frequency
V_S = ±18V, V_O = 3V_{RMS}, Differential Input
R_L = 600Ω, 2kΩ, 10kΩ, 80kHz BW

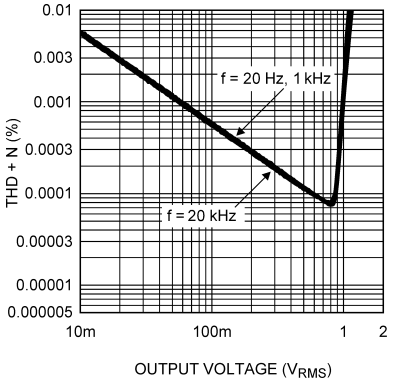


THD+N vs Frequency
V_S = ±18V, V_O = 10V_{RMS}, Differential Input
R_L = 600Ω, 2kΩ, 10kΩ, 80kHz BW

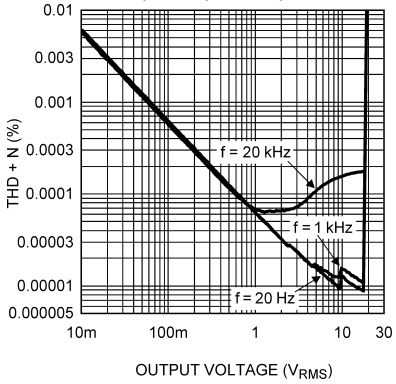


Typical Performance Characteristics (continued)

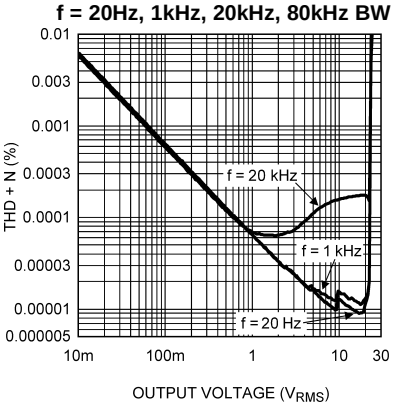
THD+N vs Output Voltage
V_S = ±2.5V, R_L = 600Ω, Differential Input
f = 20Hz, 1kHz, 20kHz, 80kHz BW



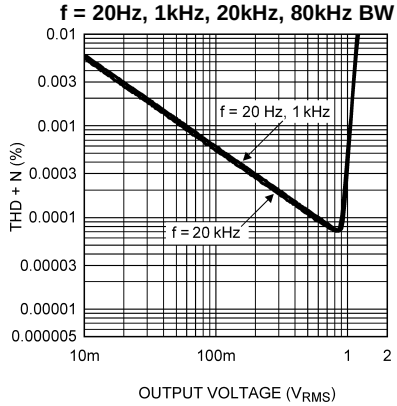
THD+N vs Output Voltage
V_S = ±15V, R_L = 600Ω, Differential Input
f = 20Hz, 1kHz, 20kHz, 80kHz BW



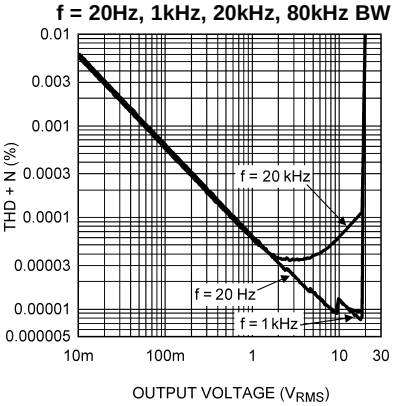
THD+N vs Output Voltage
V_S = ±18V, R_L = 600Ω, Differential Input
f = 20Hz, 1kHz, 20kHz, 80kHz BW



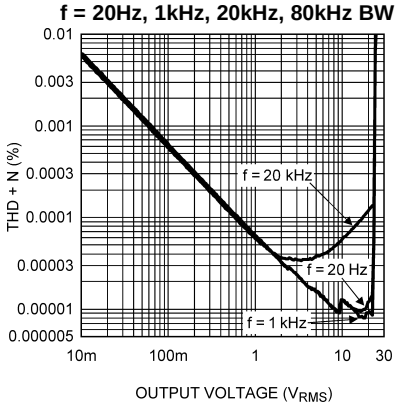
THD+N vs Output Voltage
V_S = ±2.5V, R_L = 2kΩ, Differential Input
f = 20Hz, 1kHz, 20kHz, 80kHz BW



THD+N vs Output Voltage
V_S = ±15V, R_L = 2kΩ, Differential Input
f = 20Hz, 1kHz, 20kHz, 80kHz BW

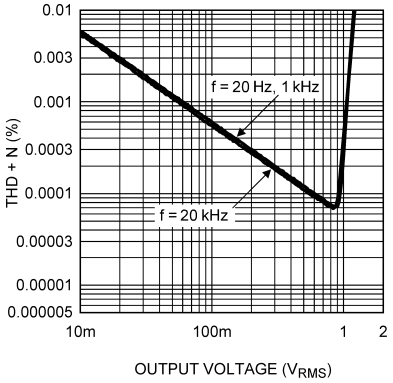


THD+N vs Output Voltage
V_S = ±18V, R_L = 2kΩ, Differential Input
f = 20Hz, 1kHz, 20kHz, 80kHz BW

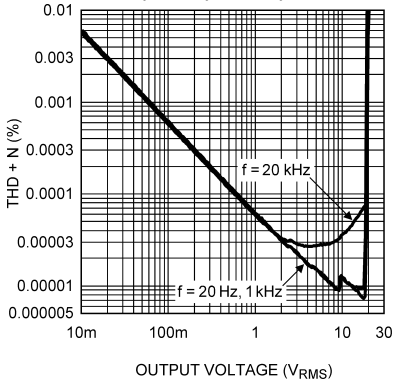


Typical Performance Characteristics (continued)

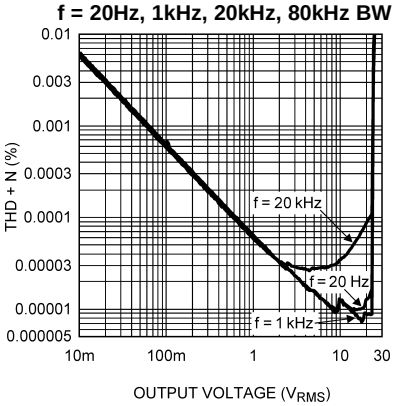
THD+N vs Output Voltage
V_S = ±2.5V, R_L = 10kΩ, Differential Input
f = 20Hz, 1kHz, 20kHz, 80kHz BW



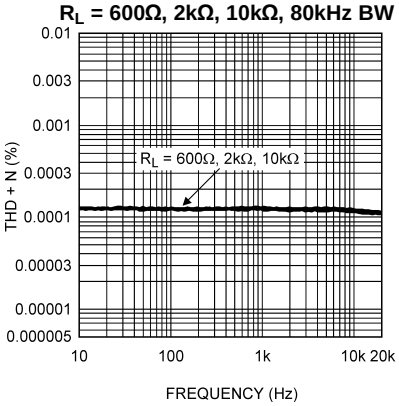
THD+N vs Output Voltage
V_S = ±15V, R_L = 10kΩ, Differential Input
f = 20Hz, 1kHz, 20kHz, 80kHz BW



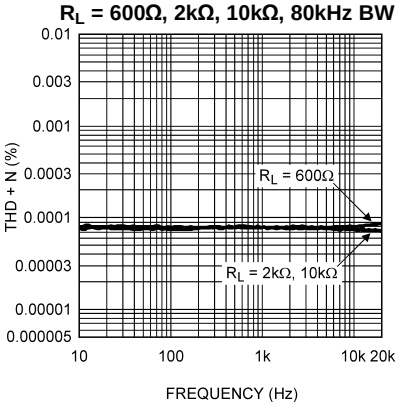
THD+N vs Output Voltage
V_S = ±18V, R_L = 10kΩ, Differential Input
f = 20Hz, 1kHz, 20kHz, 80kHz BW



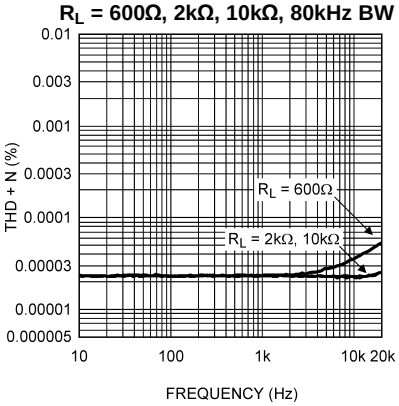
THD+N vs Frequency
V_S = ±2.5V, V_O = 0.5V_{RMS}, Single-ended Input
R_L = 600Ω, 2kΩ, 10kΩ, 80kHz BW



THD+N vs Frequency
V_S = ±2.5V, V_O = 0.8V_{RMS}, Single-ended Input
R_L = 600Ω, 2kΩ, 10kΩ, 80kHz BW

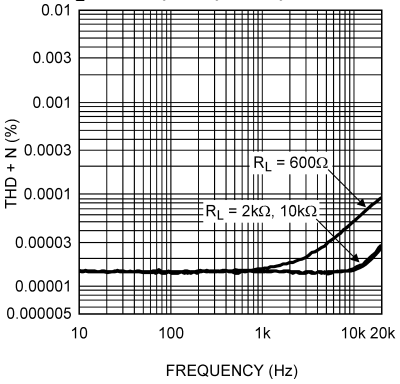


THD+N vs Frequency
V_S = ±15V, V_O = 3V_{RMS}, Single-ended Input
R_L = 600Ω, 2kΩ, 10kΩ, 80kHz BW

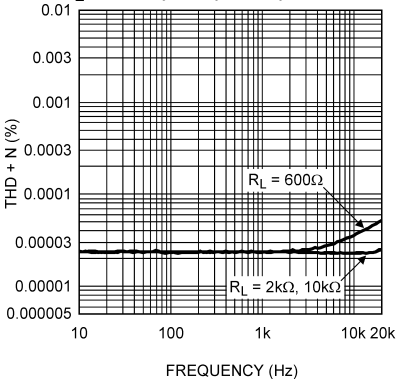


Typical Performance Characteristics (continued)

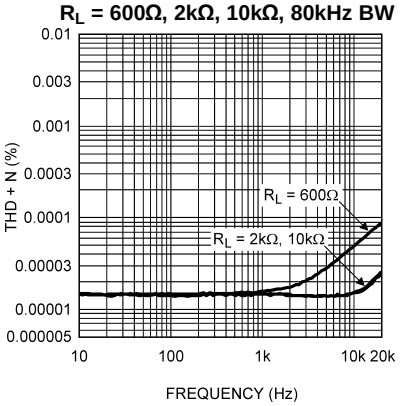
THD+N vs Frequency
V_S = ±15V, V_O = 5V_{RMS}, Single-ended Input
R_L = 600Ω, 2kΩ, 10kΩ, 80kHz BW



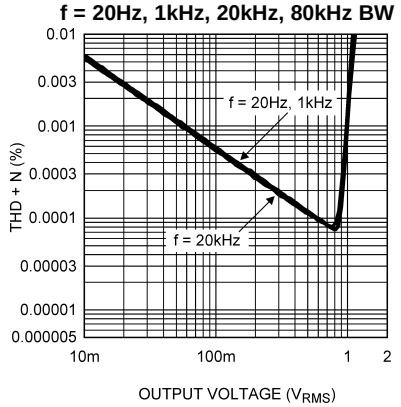
THD+N vs Frequency
V_S = ±18V, V_O = 3V_{RMS}, Single-ended Input
R_L = 600Ω, 2kΩ, 10kΩ, 80kHz BW



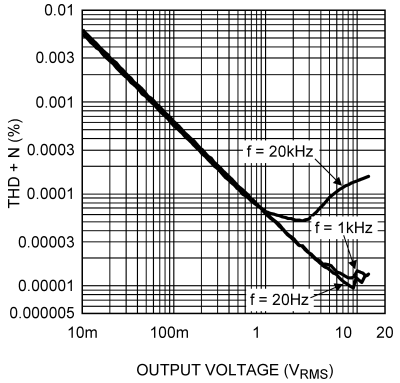
THD+N vs Frequency
V_S = ±18V, V_O = 5V_{RMS}, Single-ended Input
R_L = 600Ω, 2kΩ, 10kΩ, 80kHz BW



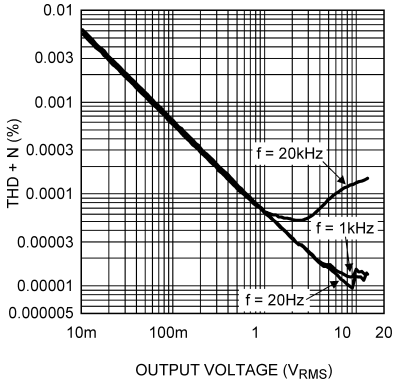
THD+N vs Output Voltage
V_S = ±2.5V, R_L = 600Ω, Single-ended Input
f = 20Hz, 1kHz, 20kHz, 80kHz BW



THD+N vs Output Voltage
V_S = ±15V, R_L = 600Ω, Single-ended Input
f = 20Hz, 1kHz, 20kHz, 80kHz BW

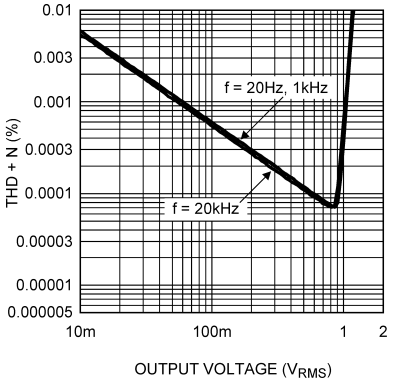


THD+N vs Output Voltage
V_S = ±18V, R_L = 600Ω, Single-ended Input
f = 20Hz, 1kHz, 20kHz, 80kHz BW

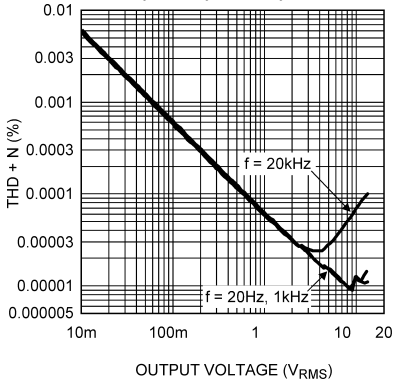


Typical Performance Characteristics (continued)

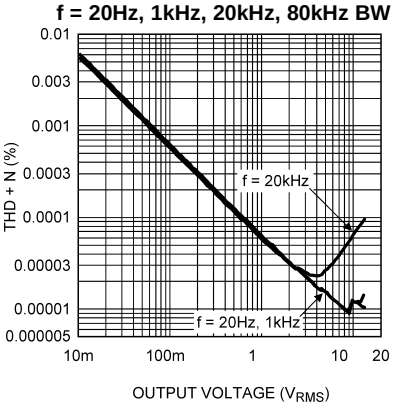
THD+N vs Output Voltage
V_S = ±2.5V, R_L = 2kΩ, Single-ended Input
f = 20Hz, 1kHz, 20kHz, 80kHz BW



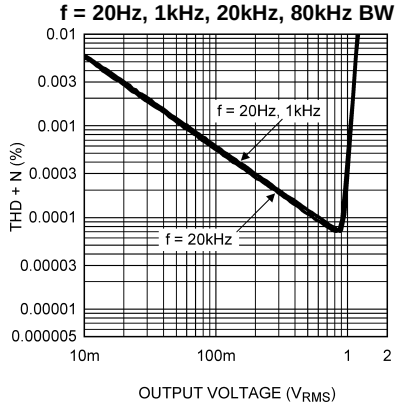
THD+N vs Output Voltage
V_S = ±15V, R_L = 2kΩ, Single-ended Input
f = 20Hz, 1kHz, 20kHz, 80kHz BW



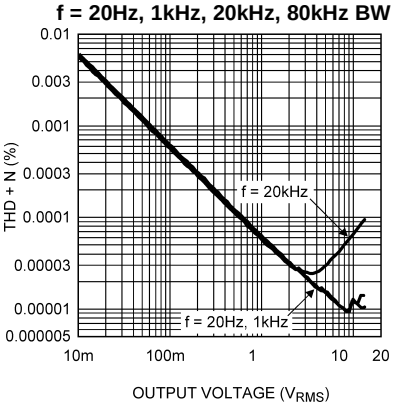
THD+N vs Output Voltage
V_S = ±18V, R_L = 2kΩ, Single-ended Input
f = 20Hz, 1kHz, 20kHz, 80kHz BW



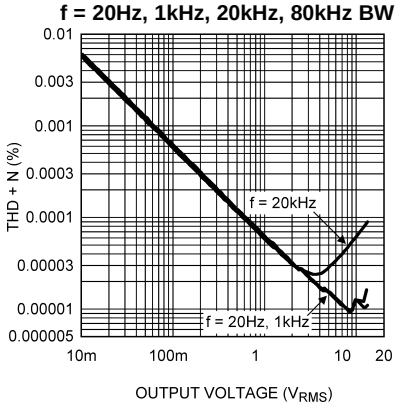
THD+N vs Output Voltage
V_S = ±2.5V, R_L = 10kΩ, Single-ended Input
f = 20Hz, 1kHz, 20kHz, 80kHz BW



THD+N vs Output Voltage
V_S = ±15V, R_L = 10kΩ, Single-ended Input
f = 20Hz, 1kHz, 20kHz, 80kHz BW

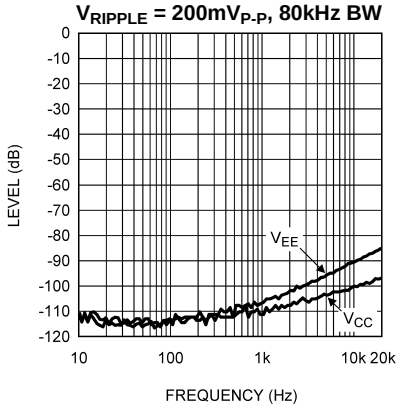


THD+N vs Output Voltage
V_S = ±18V, R_L = 10kΩ, Single-ended Input
f = 20Hz, 1kHz, 20kHz, 80kHz BW

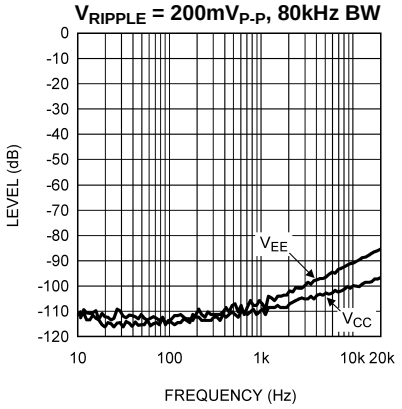


Typical Performance Characteristics (continued)

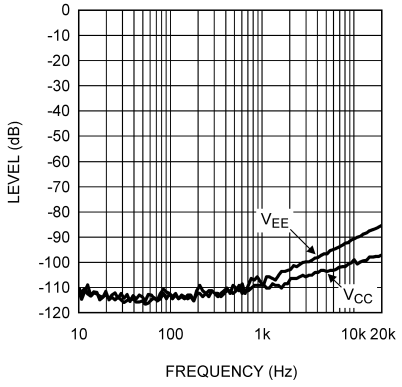
PSRR vs Frequency
V_S = ±2.5V, R_L = 600Ω, Inputs to GND
V_{RIPPLE} = 200mV_{P-P}, 80kHz BW



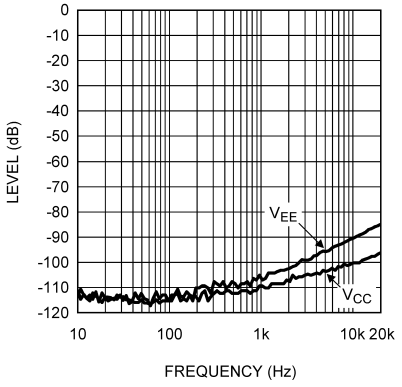
PSRR vs Frequency
V_S = ±15V, R_L = 600Ω, Inputs to GND
V_{RIPPLE} = 200mV_{P-P}, 80kHz BW



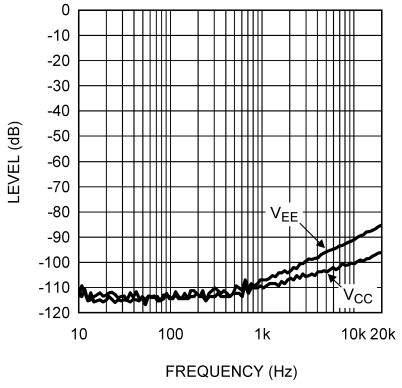
PSRR vs Frequency
V_S = ±18V, R_L = 600Ω, Inputs to GND
V_{RIPPLE} = 200mV_{P-P}, 80kHz BW



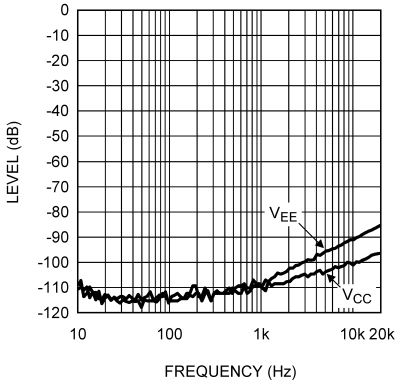
PSRR vs Frequency
V_S = ±2.5V, R_L = 2kΩ, Inputs to GND
V_{RIPPLE} = 200mV_{P-P}, 80kHz BW



PSRR vs Frequency
V_S = ±15V, R_L = 2kΩ, Inputs to GND
V_{RIPPLE} = 200mV_{P-P}, 80kHz BW

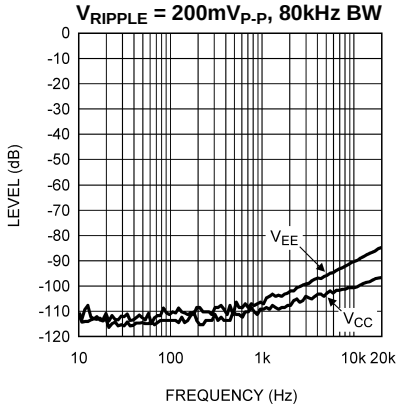


PSRR vs Frequency
V_S = ±18V, R_L = 2kΩ, Inputs to GND
V_{RIPPLE} = 200mV_{P-P}, 80kHz BW

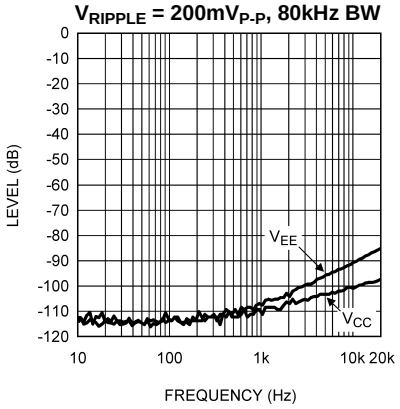


Typical Performance Characteristics (continued)

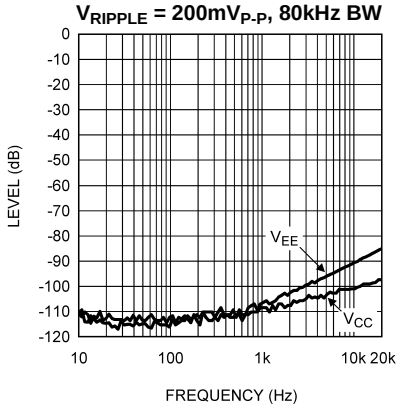
PSRR vs Frequency
V_S = ±2.5V, R_L = 10kΩ, Inputs to GND
V_{RIPPLE} = 200mV_{P-P}, 80kHz BW



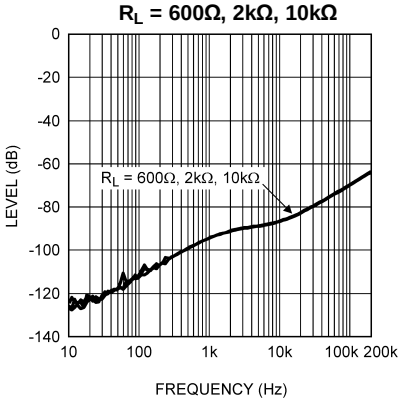
PSRR vs Frequency
V_S = ±15V, R_L = 10kΩ, Inputs to GND
V_{RIPPLE} = 200mV_{P-P}, 80kHz BW



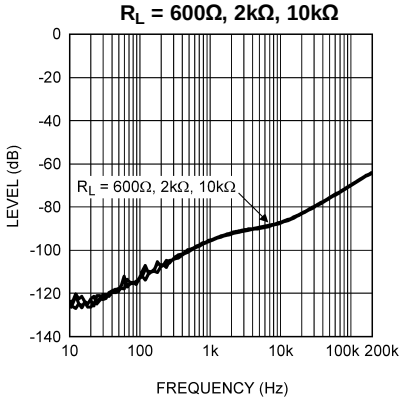
PSRR vs Frequency
V_S = ±18V, R_L = 10kΩ, Inputs to GND
V_{RIPPLE} = 200mV_{P-P}, 80kHz BW



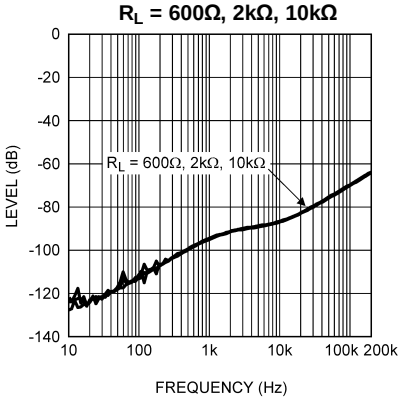
CMRR vs Frequency
V_S = ±2.5V, V_{CMRR} = 1V_{P-P}
R_L = 600Ω, 2kΩ, 10kΩ



CMRR vs Frequency
V_S = ±15V, V_{CMRR} = 1V_{P-P}
R_L = 600Ω, 2kΩ, 10kΩ

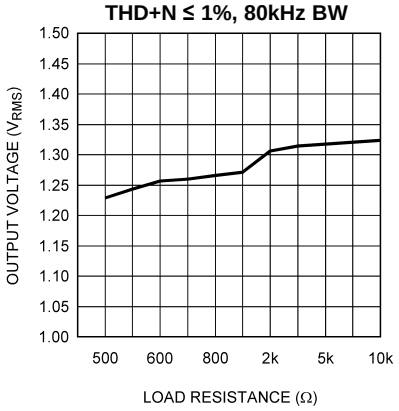


CMRR vs Frequency
V_S = ±18V, V_{CMRR} = 1V_{P-P}
R_L = 600Ω, 2kΩ, 10kΩ

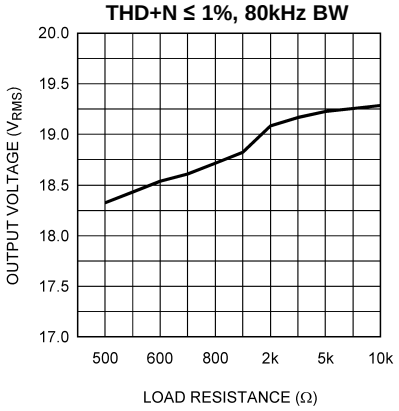


Typical Performance Characteristics (continued)

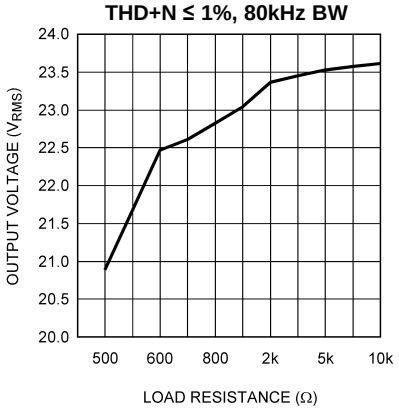
Output Voltage vs Load Resistance
V_S = ±2.5V, R_L = 500Ω – 10kΩ
THD+N ≤ 1%, 80kHz BW



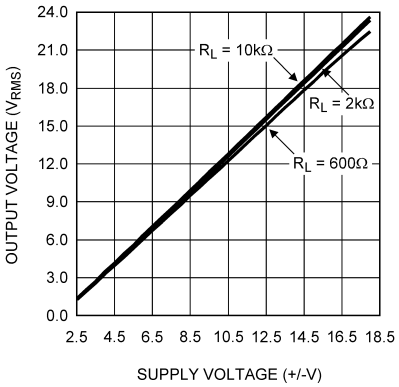
Output Voltage vs Load Resistance
V_S = ±15V, R_L = 500Ω – 10kΩ
THD+N ≤ 1%, 80kHz BW



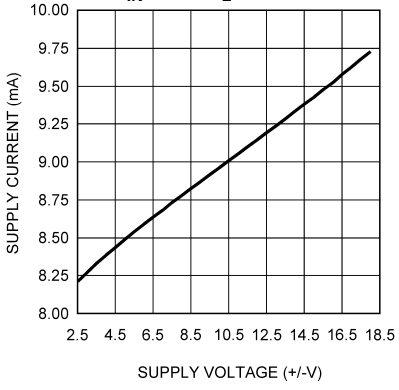
Output Voltage vs Load Resistance
V_S = ±18V, R_L = 500Ω – 10kΩ
THD+N ≤ 1%, 80kHz BW



Output Voltage vs Supply Voltage
R_L = 600Ω, 2kΩ, 10kΩ, THD+N ≤ 1%
80kHz BW



Supply Current vs Supply Voltage
V_{IN} = 0V, R_L = No Load



Application Information

GENERAL OPERATION

The LME49724 is a fully differential amplifier with an integrated common-mode reference input (V_{OCM}). Fully differential amplification provides increased noise immunity, high dynamic range, and reduced harmonic distortion products.

Differential amplifiers typically have high CMRR providing improved immunity from noise. When input, output, and supply line trace pairs are routed together, noise pick up is common and easily rejected by the LME49724. CMRR performance is directly proportional to the tolerance and matching of the gain configuring resistors. With 0.1% tolerance resistors the worst case CMRR performance will be about 60dB (20LOG(0.001)).

A differential output has a higher dynamic range than a single-ended output because of the doubling of output voltage. The dynamic range is increased by 6dB as a result of the outputs being equal in magnitude but opposite in phase. As an example, a single-ended output with a $1V_{PP}$ signal will be two $1V_{PP}$ signals with a differential output. The increase is 20LOG(2) = 6dB. Differential amplifiers are ideal for low voltage applications because of the increase in signal amplitude relative to a single-ended amplifier and the resulting improvement in SNR.

Differential amplifiers can also have reduced even order harmonics, all conditions equal, when compared to a single-ended amplifier. The differential output causes even harmonics to cancel between the two inverted outputs leaving only the odd harmonics. In practice even harmonics do not cancel completely, however there still is a reduction in total harmonic distortion.

OUTPUT COMMON-MODE VOLTAGE (V_{OCM} pin)

The output common-mode voltage is the DC voltage on each output. The output common-mode voltage is set by the V_{OCM} pin. The V_{OCM} pin can be driven by a low impedance source. If no voltage is applied to the V_{OCM} pin, the DC common-mode output voltage will be set by the internal resistor divider to the midpoint of the voltages on the V_{CC} and V_{EE} pins. The input impedance of the V_{OCM} pin is 50kΩ. The V_{OCM} pin can be driven up to V_{CC} - 1.5V and V_{EE} + 1.5V. The V_{OCM} pin should be bypassed to ground with a 0.1µF to 1µF capacitor. The V_{OCM} pin should be connected to ground when the desired output common-mode voltage is ground reference. The value of the external capacitor has an effect on the PSRR performance of the LME49724. With the V_{OCM} pin only bypassed with a low value capacitor, the PSRR performance of the LME49724 will be reduced, especially at low audio frequencies. For best PSRR performance, the V_{OCM} pin should be connected to stable, clean reference. Increasing the value of the bypass capacitor on the V_{OCM} pin will also improve PSRR performance.

ENABLE FUNCTION

The LME49724 can be placed into standby mode to reduce system current consumption by driving the ENABLE pin below V_{EE} + 1.75V. The LME49724 is active when the voltage on the ENABLE pin is above V_{EE} + 2.35V. The ENABLE pin should not be left floating. For best performance under all conditions, drive the ENABLE pin to the V_{EE} pin voltage to enter standby mode and to ground for active operation when operating from split supplies. When operating from a single supply, drive the ENABLE pin to ground for standby mode and to V_{CC} for active mode.

FULLY DIFFERENTIAL OPERATION

The LME49724 performs best in a fully differential configuration. The circuit shown in Figure 2 is the typical fully differential configuration.

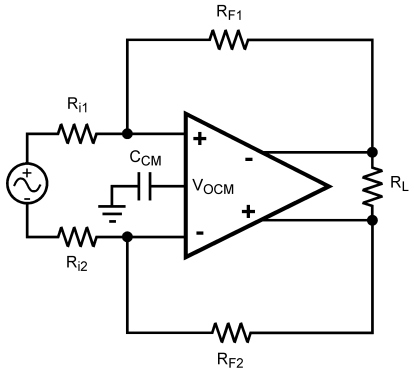


Figure 4. Fully Differential Configuration

The closed-loop gain is shown in Equation 1 below.

$$A_V = R_F / R_i \quad (V/V) \tag{1}$$

Where $R_{F1} = R_{F2}$, $R_{i1} = R_{i2}$. Using low value resistors will give the lowest noise performance.

SINGLE-ENDED TO DIFFERENTIAL CONVERSION

For many applications, it is required to convert a single-ended signal to a differential signal. The LME49724 can be used for a high performance, simple single-to-differential converter. Figure 3 shows the typical single-to-differential converter circuit configuration.

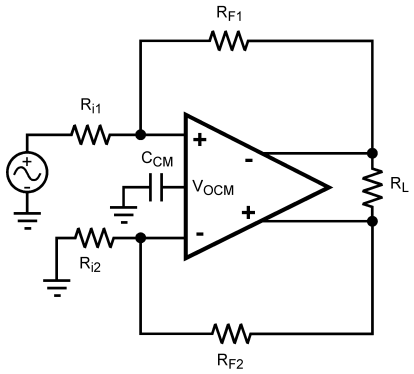


Figure 5. Single-Ended Input to Differential Output

SINGLE SUPPLY OPERATION

The LME49724 can be operated from a single power supply, as shown in Figure 4. The supply voltage range is limited to a minimum of 5V and a maximum of 36V. The common-mode output DC voltage will be set to the midpoint of the supply voltage. The V_{OCM} pin can be used to adjust the common-mode output DC voltage on the outputs, as described previously, if the supply voltage midpoint is not the desired DC voltage.

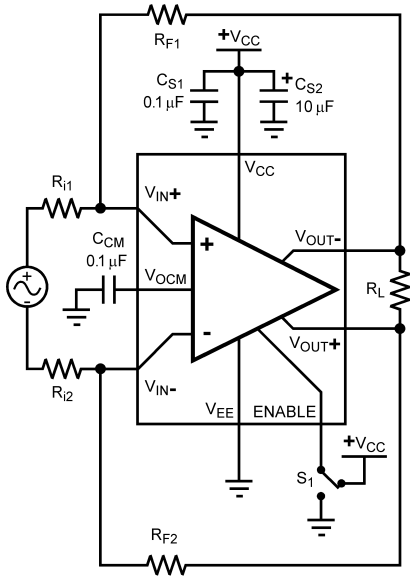


Figure 6. Single Supply Configuration

DRIVING A CAPACITIVE LOAD

The LME49724 is a high speed op amp with excellent phase margin and stability. Capacitive loads up to 100pF will cause little change in the phase characteristics of the amplifiers and are therefore allowable.

Capacitive loads greater than 100pF must be isolated from the output. The most straightforward way to do this is to put a resistor in series with the output. This resistor will also prevent excess power dissipation if the output is accidentally shorted.

THERMAL PCB DESIGN

The LME49724's high operating supply voltage along with its high output current capability can result in significant power dissipation. For this reason the LME49724 is provided in the exposed DAP MSOP (PSOP) package for improved thermal dissipation performance compared to other surface mount packages. The exposed pad is designed to be soldered to a copper plane on the PCB which then acts as a heat sink. The thermal plane can be on any layer by using multiple thermal vias under and outside the IC package. The vias under the IC should have solder mask openings for the entire pad under the IC on the top layer but cover the vias on the bottom layer. This method prevents solder from being pulled away from the thermal vias during the reflow process resulting in optimum thermal conductivity.

Heat radiation from the PCB plane area is best accomplished when the thermal plane is on the top or bottom copper layers. The LME49724 should always be soldered down to a copper pad on the PCB for both optimum thermal performance as well as mechanical stability.

The exposed pad is for heat transfer and the thermal plane should either be electrically isolated or connected to the same potential as the V_{EE} pin. For high frequency applications (f > 1MHz) or lower impedance loads, the pad should be connected to a plane that is connected to the V_{EE} potential.

SUPPLY BYPASSING

The LME49724 should have its supply leads bypassed with low-inductance capacitors such as leadless surface mount (SMT) capacitors located as close as possible to the supply pins. It is recommended that a 10µF tantalum or electrolytic capacitor be placed in parallel with a 0.1µF ceramic or film type capacitor on each supply pin. These capacitors should be star routed with a dedicated ground return plane or large trace for best THD performance. Placing capacitors too far from the power supply pins, especially with thin connecting traces, can lead to excessive inductance, resulting in degraded high-frequency bypassing. Poor high-frequency bypassing can result in circuit instabilities. When using high bandwidth power supplies, the value and number of supply bypass capacitors should be reduced for optimal power supply performance.

BALANCE CABLE DRIVER

With high peak-to-peak differential output voltage and plenty of low distortion drive current, the LME49724 makes an excellent balanced cable driver. Combining the single-to-differential configuration with a balanced cable driver results in a high performance single-ended input to balanced line driver solution.

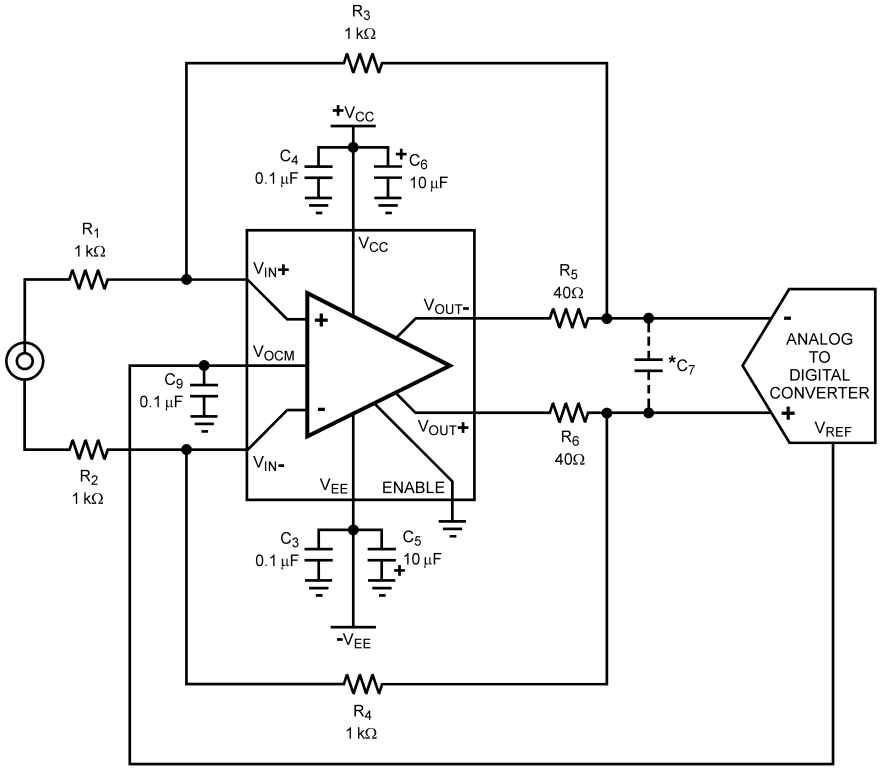
Although the LME49724 can drive capacitive loads up to 100pF, cable loads exceeding 100pF can cause instability. For such applications, series resistors are needed on the outputs before the capacitive load.

ANALOG-TO-DIGITAL CONVERTER (ADC) APPLICATION

Figure 5 is a typical fully differential application circuit for driving an analog-to-digital converter (ADC). The additional components of R_5, R_6, and C_7 are optional components and are for stability and proper ADC sampling. ADC's commonly use switched capacitor circuitry at the input. When the ADC samples the signal the current momentarily increases and may disturb the signal integrity at the sample point causing a signal glitch. Component C_7 is significantly larger than the input capacitance of a typical ADC and acts as a charge reservoir greatly reducing the effect of the signal sample by the ADC. Resistors R_5 and R_6 decouple the capacitive load, C_7, for stability. The values shown are general values. Specific values should be optimized for the particular ADC loading requirements.

The output reference voltage from the ADC can be used to drive the V_{OCM} pin to set the common-mode DC voltage on the outputs of the LME49724. A buffer may be needed to drive the LME49724's V_{OCM} pin if the ADC cannot drive the 50kΩ input impedance of the V_{OCM} pin.

In order to minimize circuit distortion when using capacitors in the signal path, the capacitors should be comprised of either NPO ceramic, polystyrene, polypropylene or mica composition. Other types of capacitors may provide a reduced distortion performance but for a cost improvement, so capacitor selection is dependent upon design requirements. The performance/cost tradeoff for a specific application is left up to the user.



***** Value is application and converted dependent.

Figure 7. Typical Analog-to-Digital Converter Circuit

DISTORTION MEASUREMENTS

The vanishing low residual distortion produced by the LME49724 is below the capabilities of commercially available equipment. This makes distortion measurements more difficult than simply connecting a distortion meter to the amplifier's inputs and outputs. The solution, however, is quite simple: an additional resistor. Adding this resistor extends the resolution of the distortion measurement equipment.

The LME49724's low residual distortion is an input referred internal error. As shown in Figure 6, adding a resistor connected between the amplifier's inputs changes the amplifier's noise gain. The result is that the error signal (distortion) is increased. Although the amplifier's closed-loop gain is unaltered, the feedback available to correct distortion errors is reduced, which means that measurement resolution increases. To ensure minimum effects on distortion measurements, keep the value of R_5 low. The distortion reading on the audio analyzer must be divided by a factor of $(R_3 + R_4)/R_5$, where $R_1 = R_2$ and $R_3 = R_4$, to get the actual measured distortion of the device under test. The values used for the LME49724 measurements were R_1, R_2, R_3, R_4 = 1kΩ and R_5 = 20Ω.

This technique is verified by duplicating the measurements with high closed-loop gain and/or making the measurements at high frequencies. Doing so produces distortion components that are within the measurement equipment's capabilities.

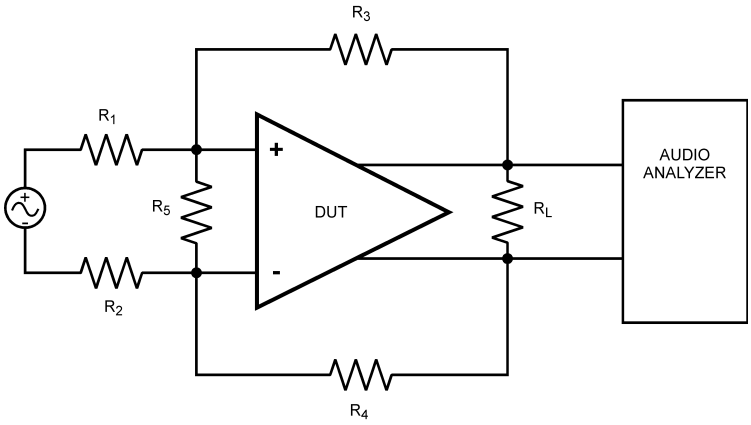


Figure 8. THD+N and IMD Distortion Test Circuit

PERFORMANCE VARIATIONS

The LME49724 has excellent performance with little variation across different supply voltages, load impedances, and input configuration (single-ended or differential). Inspection of the THD+N vs Frequency and THD+N vs Output Voltage performance graphs reveals only minimal differences with different load values. Figures 7 and 8 below show the performance across different supply voltages with the same output signal level and load. Figure 7 has plots at ±5V, ±12V, ±15V, and ±18V with a $3V_{RMS}$ output while Figure 8 has plots at ±12V, ±15V, and ±18V with a $10V_{RMS}$ output. Both figures use a 600Ω load. The performance for each different supply voltage under the same conditions is so similar it is nearly impossible to discern the different plots lines.

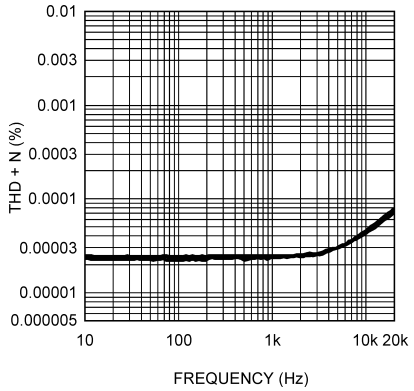


Figure 9. THD+N vs FREQUENCY with R_L = 600Ω
V_{OUT} = 3V_{RMS}, Differential Input, 80kHz BW
V_S = ±5V, ±12V, ±15V, and ±18V

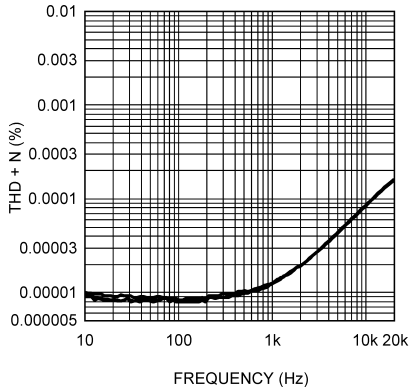


Figure 10. THD+N vs FREQUENCY with R_L = 600Ω
V_{OUT} = 10V_{RMS}, Differential Input, 80kHz BW
V_S = ±12V, ±15V, and ±18V

Whether the input configuration is single-ended or differential has only a minimal affect on THD+N performance at higher audio frequencies or higher signal levels. For easy comparison, Figures 9 and 10 are a combination of the performance graphs found in the *Typical Performance Characteristics* section above.

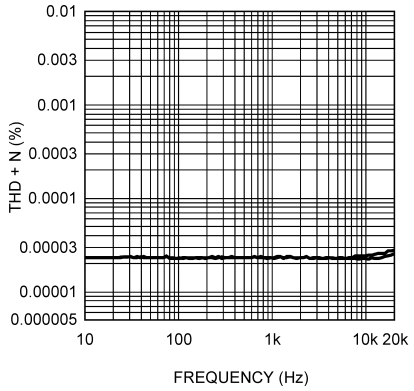


Figure 11. THD+N vs FREQUENCY with R_L = 10kΩ
V_{OUT} = 3V_{RMS}, V_S = ±15V, 80kHz BW
Single-ended and Differential Input

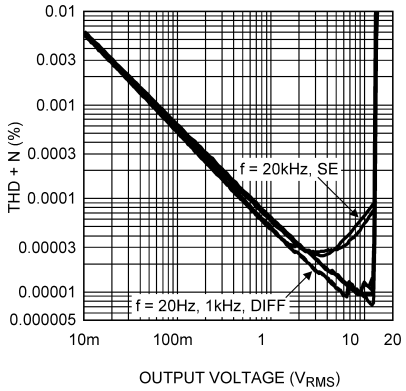


Figure 12. THD+N vs OUTPUT VOLTAGE with R_L = 10kΩ
f = 20Hz, 1kHz, 20kHz, V_S = ±15V, 80kHz BW
Single-ended and Differential Input

Power Supply Rejection Ratio does not vary with load value nor supply voltage. For easy comparison, Figures 11 and 12 below are created by combining performance graphs found in the *Typical Performance Characteristics* section above.

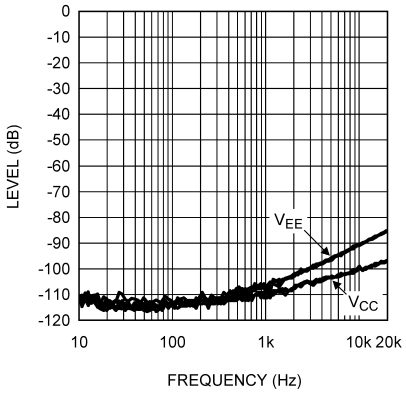


Figure 13. PSRR vs FREQUENCY with R_L = 600Ω
V_S = ±2.5V, ±15V, and ±18V, 80kHz BW

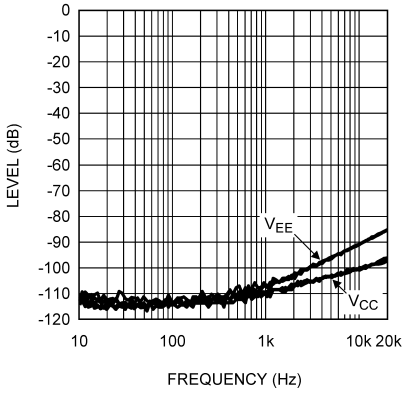


Figure 14. PSRR vs FREQUENCY with V_S = ±15V
R_L = 600Ω, 2kΩ, and 10kΩ, 80kHz BW

Although supply current may not be a critical specification for many applications, there is also no real variation in supply current with no load or with a 600Ω load. This is a result of the extremely low offset voltage, typically less than 1mV. Figure 13 shows the supply current under the two conditions with no real difference discernable.

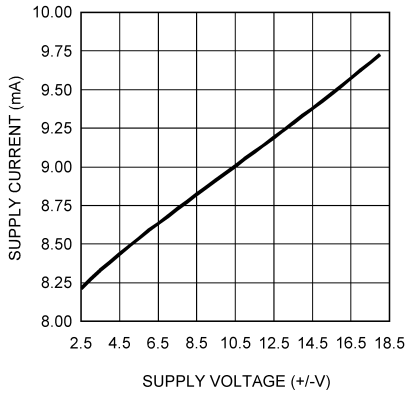


Figure 15. Supply Current vs Supply Voltage
R_L = No Load and 600Ω

Demo Board Schematic

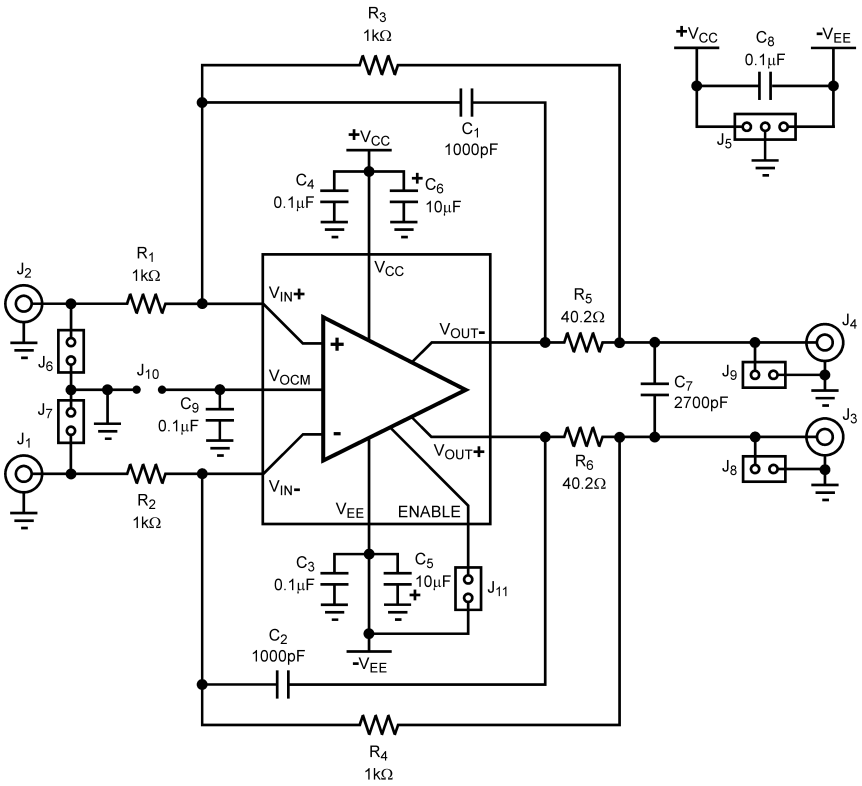


Figure 16. Demonstration Board Circuit

Build of Materials

Table 2. Reference Demo Board Bill of Materials

Designator	Value	Tolerance	Part Description	Comment
R_1, R_2, R_3, R_4	1kΩ	1%	1/8W, 0603 Resistor	

Table 2. Reference Demo Board Bill of Materials (continued)

Designator	Value	Tolerance	Part Description	Comment
R_5, R_6	40.2Ω	1%	1/8W, 0603 Resistor	
C_1, C_2	1000pF	10%	0603, NPO Ceramic Capacitor, 50V	
C_3, C_4, C_8, C_9	0.1µF	–20%, +80%	0603, Y5V Ceramic Capacitor, 25V	
C_5, C_6	10µF	20%	Size C (6032), Tantalum Capacitor, 25V	
C_7	2700pF	10%	0805, NPO Ceramic Capacitor, 50V	
U_1			LME49724MR	
J_1, J_2, J_3, J_4			SMA coaxial connector	Inputs & Outputs
J_5			0.100" 1x3 header, vertical mount	V_{DD}, V_{EE}, GND
J_6, J_7, J_8, J_9, J_{10}, J_{11}			0.100" 1x2 header, vertical mount	Inputs, Outputs, V_{OCM}, Enable

Revision History

Rev	Date	Description
1.0	11/12/08	Initial release.

PACKAGING INFORMATION

Orderable Device	Status (1)	Package Type	Package Drawing	Pins	Package Qty	Eco Plan (2)	Lead/Ball Finish	MSL Peak Temp (3)	Op Temp (°C)	Top-Side Markings (4)	Samples
LME49724MR/NOPB	ACTIVE	SO PowerPAD	DDA	8	95	Green (RoHS & no Sb/Br)	CU SN	Level-3-260C-168 HR	-40 to 85	L49724 MR	Samples
LME49724MRX/NOPB	ACTIVE	SO PowerPAD	DDA	8	2500	Green (RoHS & no Sb/Br)	CU SN	Level-3-260C-168 HR	-40 to 85	L49724 MR	Samples

(1) The marketing status values are defined as follows:
ACTIVE: Product device recommended for new designs.
LIFEBUY: TI has announced that the device will be discontinued, and a lifetime-buy period is in effect.
NRND: Not recommended for new designs. Device is in production to support existing customers, but TI does not recommend using this part in a new design.
PREVIEW: Device has been announced but is not in production. Samples may or may not be available.
OBSOLETE: TI has discontinued the production of the device.

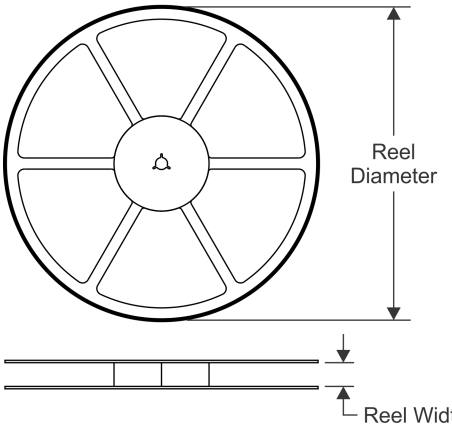
(2) Eco Plan - The planned eco-friendly classification: Pb-Free (RoHS), Pb-Free (RoHS Exempt), or Green (RoHS & no Sb/Br) - please check http://www.ti.com/productcontent for the latest availability information and additional product content details.
TBD: The Pb-Free/Green conversion plan has not been defined.
Pb-Free (RoHS): TI's terms "Lead-Free" or "Pb-Free" mean semiconductor products that are compatible with the current RoHS requirements for all 6 substances, including the requirement that lead not exceed 0.1% by weight in homogeneous materials. Where designed to be soldered at high temperatures, TI Pb-Free products are suitable for use in specified lead-free processes.
Pb-Free (RoHS Exempt): This component has a RoHS exemption for either 1) lead-based flip-chip solder bumps used between the die and package, or 2) lead-based die adhesive used between the die and leadframe. The component is otherwise considered Pb-Free (RoHS compatible) as defined above.
Green (RoHS & no Sb/Br): TI defines "Green" to mean Pb-Free (RoHS compatible), and free of Bromine (Br) and Antimony (Sb) based flame retardants (Br or Sb do not exceed 0.1% by weight in homogeneous material)

(3) MSL, Peak Temp. -- The Moisture Sensitivity Level rating according to the JEDEC industry standard classifications, and peak solder temperature.

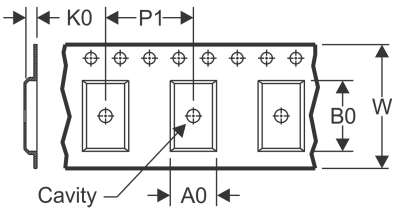
(4) Only one of markings shown within the brackets will appear on the physical device.

TAPE AND REEL INFORMATION

REEL DIMENSIONS

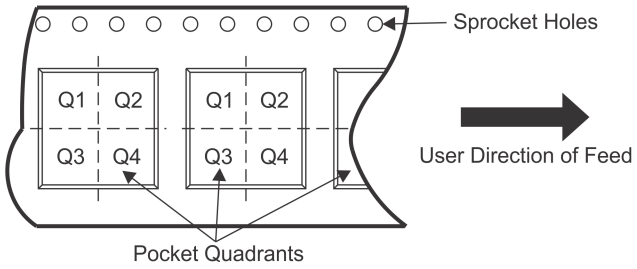


TAPE DIMENSIONS



A0	Dimension designed to accommodate the component width
B0	Dimension designed to accommodate the component length
K0	Dimension designed to accommodate the component thickness
W	Overall width of the carrier tape
P1	Pitch between successive cavity centers

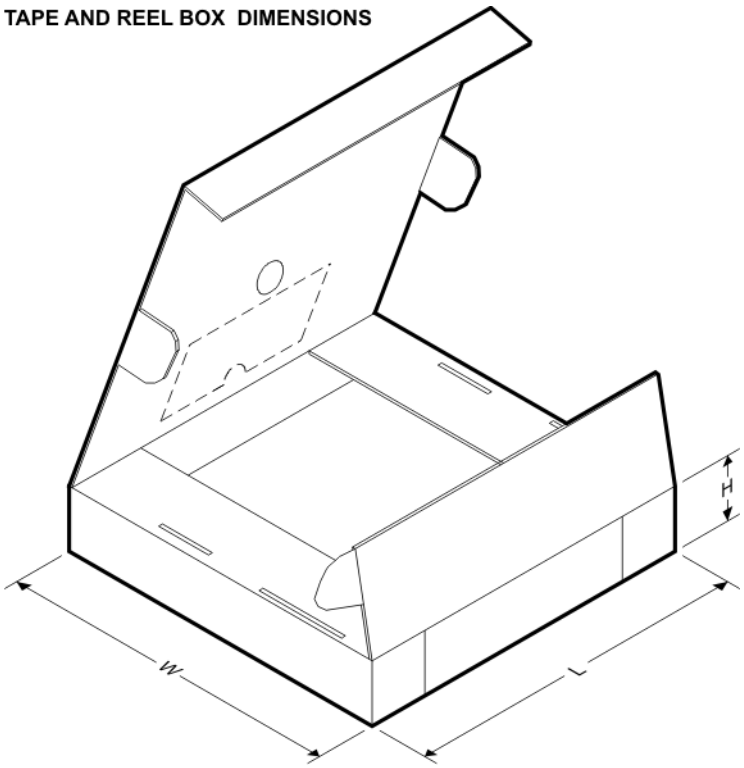
QUADRANT ASSIGNMENTS FOR PIN 1 ORIENTATION IN TAPE



*All dimensions are nominal

Device	Package Type	Package Drawing	Pins	SPQ	Reel Diameter (mm)	Reel Width W1 (mm)	A0 (mm)	B0 (mm)	K0 (mm)	P1 (mm)	W (mm)	Pin1 Quadrant
LME49724MRX/NOPB	SO Power PAD	DDA	8	2500	330.0	12.4	6.5	5.4	2.0	8.0	12.0	Q1

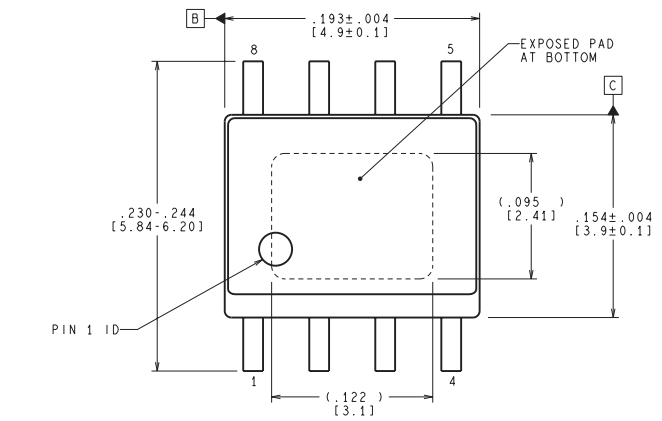
TAPE AND REEL BOX DIMENSIONS

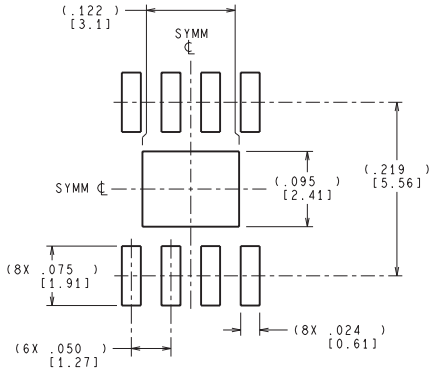


*All dimensions are nominal

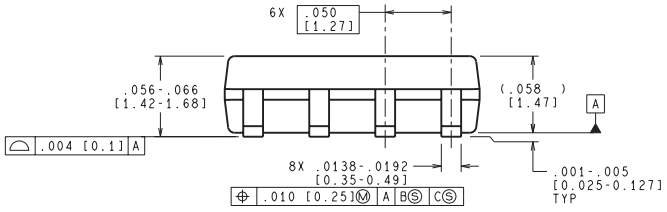
Device	Package Type	Package Drawing	Pins	SPQ	Length (mm)	Width (mm)	Height (mm)
LME49724MRX/NOPB	SO PowerPAD	DDA	8	2500	358.0	343.0	63.0

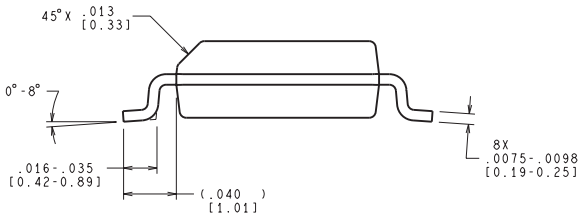
DDA0008B





RECOMMENDED LAND PATTERN





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